

Features

- Trench Power LV MOSFET Technology
- · High Speed Switching
- High Density Cell Design for Low R_{DS(ON)}
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- · Moisture Sensitivity Level 1

Maximum Ratings

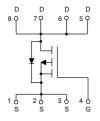
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 5.9°C/W Junction to Case⁽²⁾

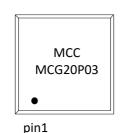
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	-20	Α
Pulsed Drain Current ⁽³⁾	I _{DM}	-80	Α
Total Power Dissipation T _C =25°C	P _D	21	W

Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.
- 3. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

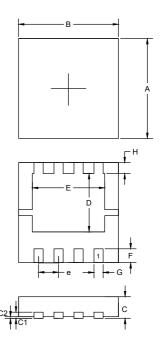
Internal Structure and Marking Code





P-CHANNEL MOSFET

DFN3333



	DIMENSIONS				
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.126	0.130	3.20	3.30	
В	0.126	0.130	3.20	3.30	
С	0.030	0.033	0.75	0.85	
C1	0.007	0.009	0.18	0.22	
C2		0.002		0.05	
D	0.071	0.079	1.80	2.00	
Е	0.087	0.098	2.20	2.50	
F	0.016	0.020	0.40	0.50	
G	0.010	0.014	0.25	0.35	
Н	0.012	0.016	0.30	0.40	
е	0.024	0.028	0.60	0.70	

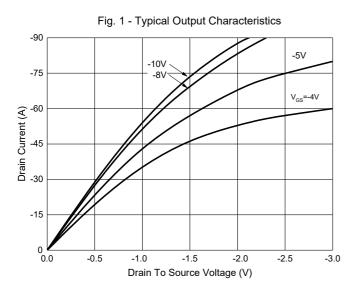


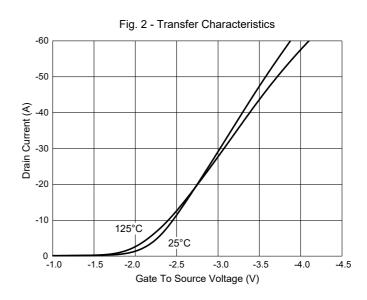
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

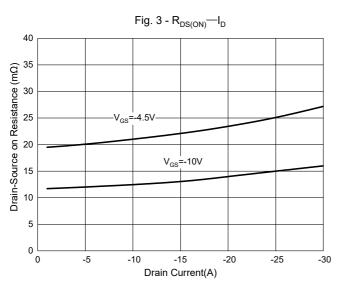
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics				1	1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-30			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.5	-2.5	V	
Drain-Source On-Resistance		V _{GS} =-10V, I _D =-10A		13.5	20	mΩ	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-5A		20	27	mΩ	
Gate Resistance	R _g	f=1 MHz, Open drain		7.5		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				-20	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-20A			-1.2	V	
Reverse Recovery Time	t _{rr}	L 0A H / H 500A /		14		ns	
Reverse Recovery Charge	Q _{rr}	l _F =-9A, dl _F /dt=500A/μs		6		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			1750			
Output Capacitance	C _{oss}	V _{DS} =-15V,V _{GS} =0V,f=1MHz		220		pF	
Reverse Transfer Capacitance	C _{rss}			185		•	
Total Gate Charge	Qg			28.7			
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,V _{GS} =-10V,I _D =-9A		5.5		nC	
Gate-Drain Charge	Q_{gd}			5.4			
Turn-On Delay Time	t _{d(on)}			10			
Turn-On Rise Time	t _r	V _{DS} =-15V, V _{GEN} =-10V,		44		no	
Turn-Off Delay Time	t _{d(off)}	$R_G=2.5\Omega$, $I_{DS}=-6A$		54		ns	
Turn-Off Fall Time	t _f			59			

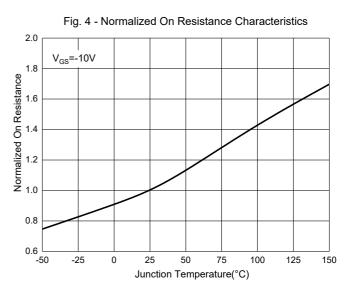


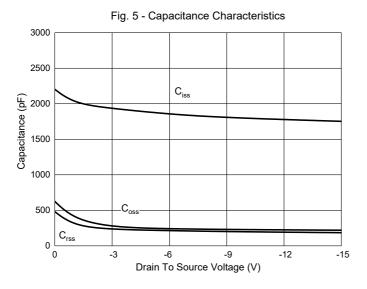
Curve Characteristics

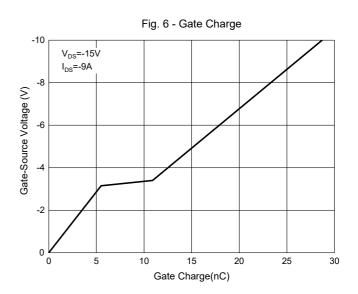














Curve Characteristics

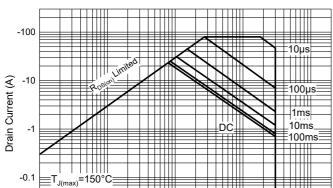
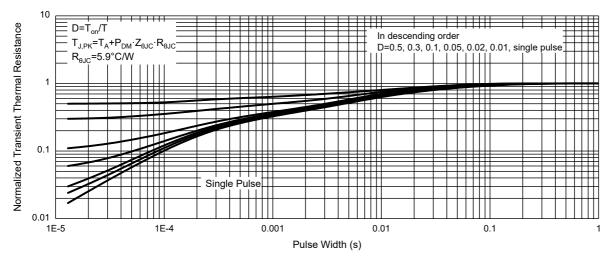


Fig. 7 - Safe Operation Area

T_{J(max)}=150°C T_C=25°C Single Pulse -0.01 -0.01 -0.1 -100 Drain-Source Voltage (V)

Fig. 8 - Normalized Transient Thermal Impedance



Rev.3-2-04092022 MCCSEMI.COM



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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